



Toward high-endurance nonvolatile reconfigurable metasurfaces

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Cosmin-Constantin Popescu, Steven Vitale, Tian Gu, and Juejun Hu

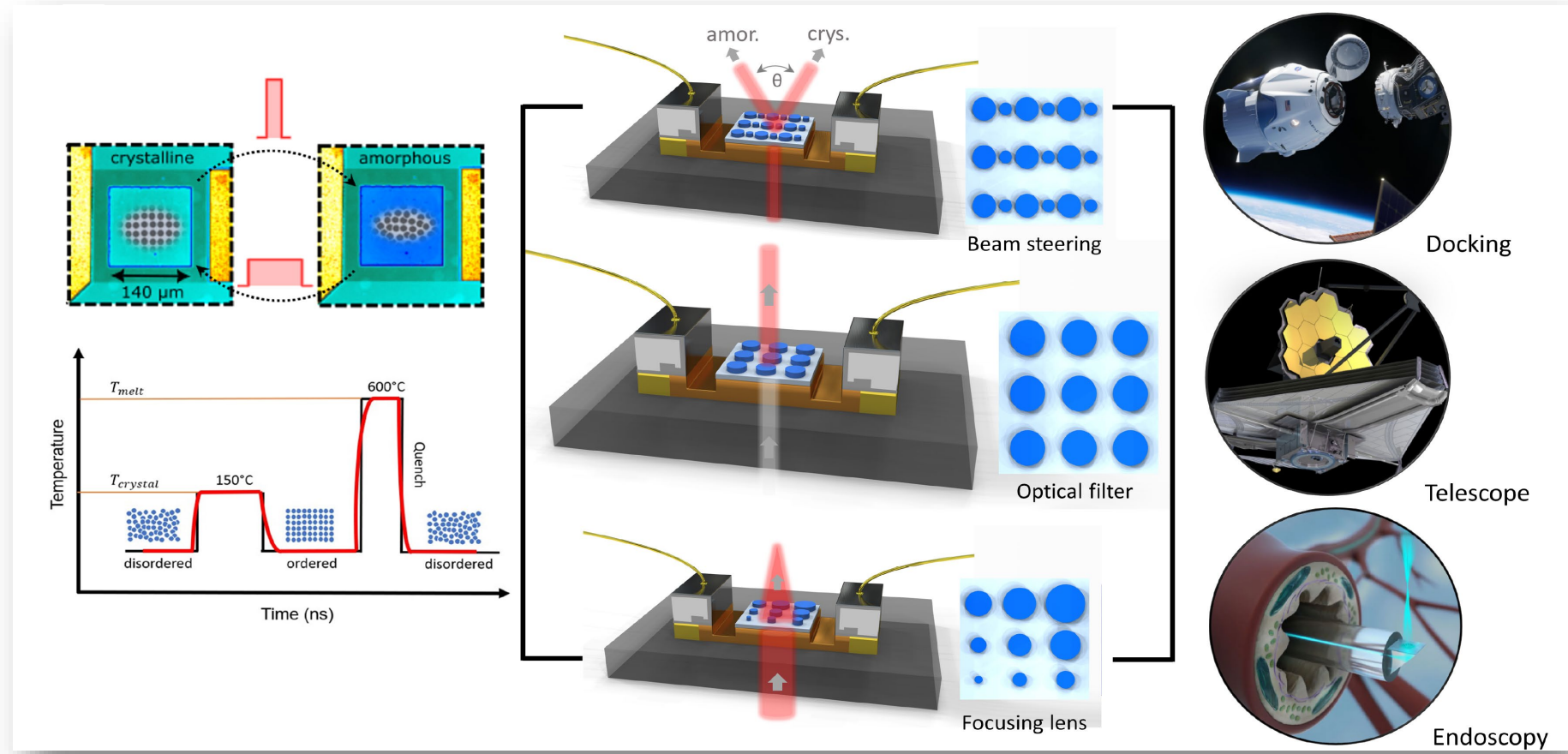
Hyung Bin Bae and Taewoo Lee

Why is NASA researching reconfigurable metasurfaces?



- “Cutting edge innovations by NASA leaderships seek to refine **scientific instrument into smaller, lighter, more versatile** tools for exploration” – *Karl Hille, chief technologist at NASA’s GSFC*
- “**Metasurface optic** technologies are important because of the **precision and versatility** that it offers to LiDAR” – *Cheryl Gramling, assistant chief for technology at GSFC*
- “As recently displayed by the stunning images from the JWST, we often rely on recording the intensity of light (e.g., with a camera) to study the universe. ...**Metasurfaces** enable general manipulations of phase, amplitude, and polarization on the nanoscale, thereby providing **ample opportunity**and even **enable functionality not possible using conventional technologies** - *Tobias Wenger, researcher at JPL*
- ... “NASA scientists are on the cusp of revolutionizing LEO Earth Observing platforms using novel optical **metamaterials to reduce the size, weight and power (SWaP) of existing architectures.**”
– *William Humphreys, chief engineer at LaRC*
- **Metamaterials** are man-made (synthesized) composite materials whose electromagnetic, acoustic, optical, etc. properties are determined by their constitutive structural materials and their configurations. In the field of electromagnetic research and beyond, metamaterials offer **excellent design flexibility with their customized properties and their tunability under external stimuli**

Why is NASA researching nonvolatile reconfigurable metasurfaces?



Mission Need

Metasurface-based optics capable of generating actively-tunable focus, arbitrary optical wavefronts at **ultrafast speeds, with sub-wavelength resolution, and without moving parts.**

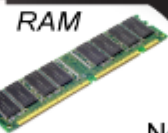
PCM-based reconfigurable metasurfaces



Phase Change Materials

Memory

1960s



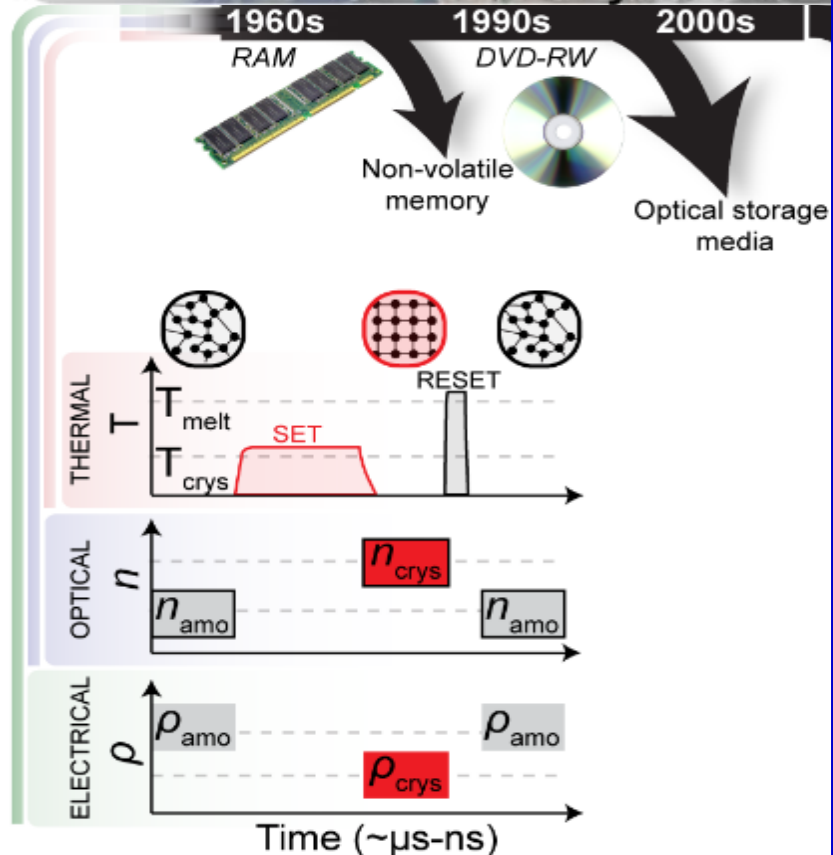
1990s



2000s

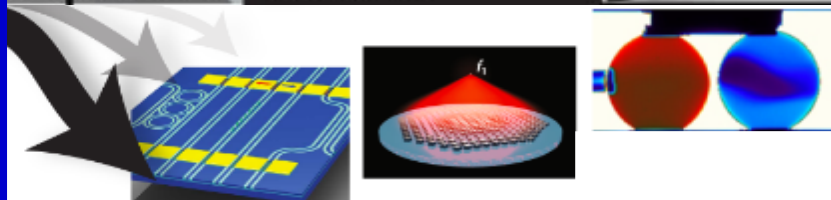
Optical storage media

Non-volatile memory



Optical

2020 -



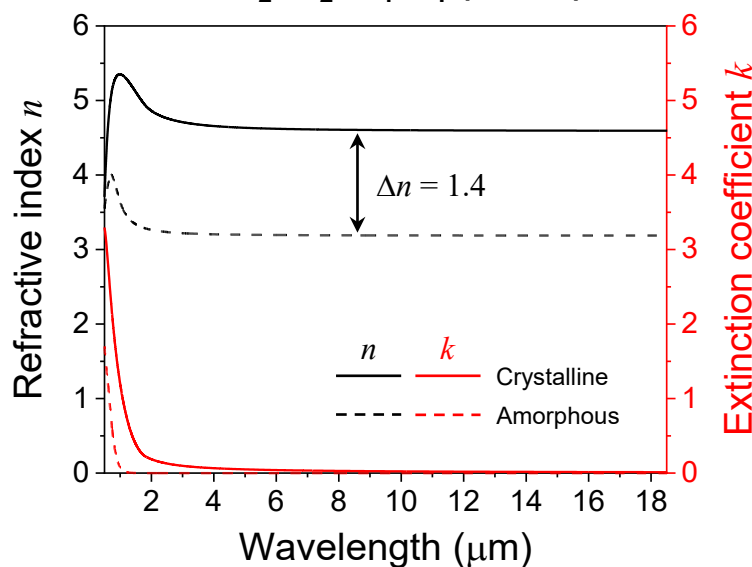
Space

Spaceborne photonics and electronics

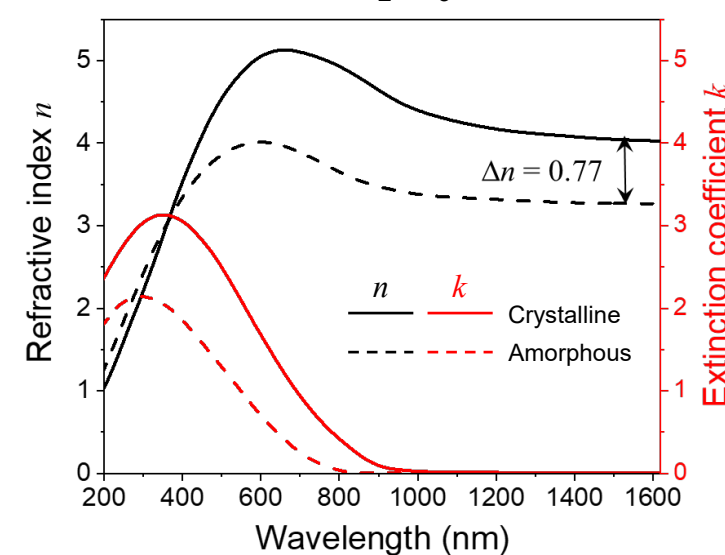
- + Fast tuning
- + Radiation tolerance
- + Large Δn
- + Wide waveband
- + Non-volatility



$\text{Ge}_2\text{Sb}_2\text{Se}_4\text{Te}_1$ (GSST)



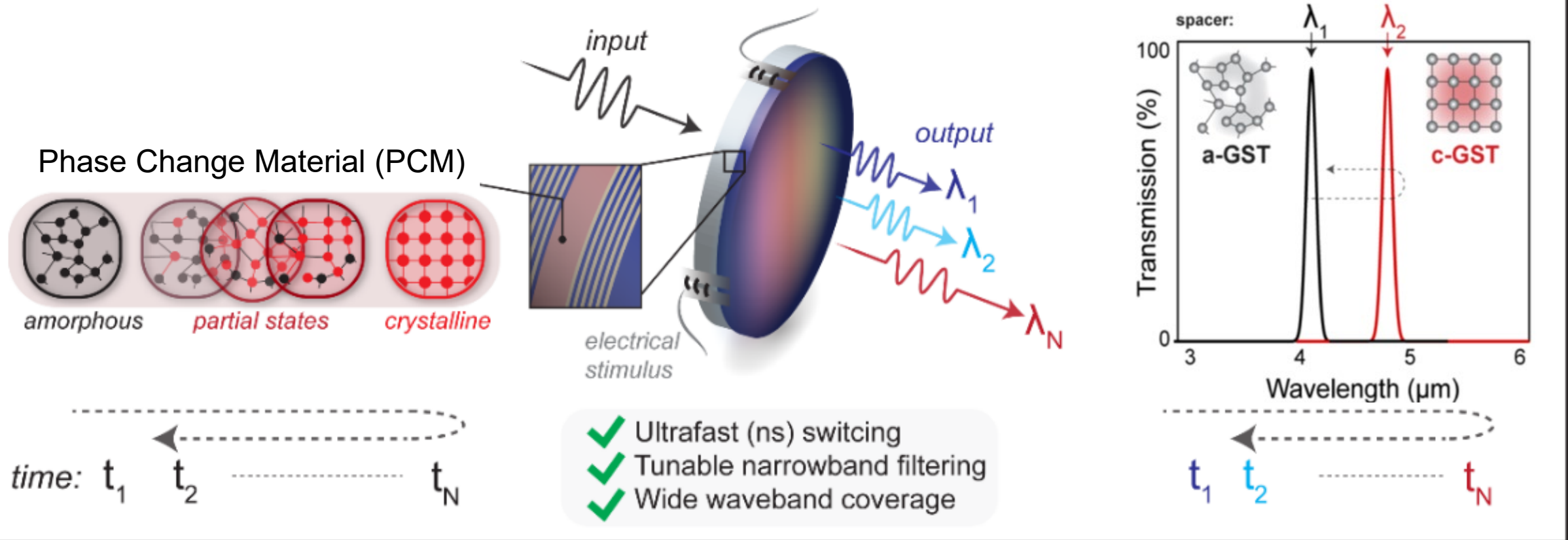
Sb_2Se_3



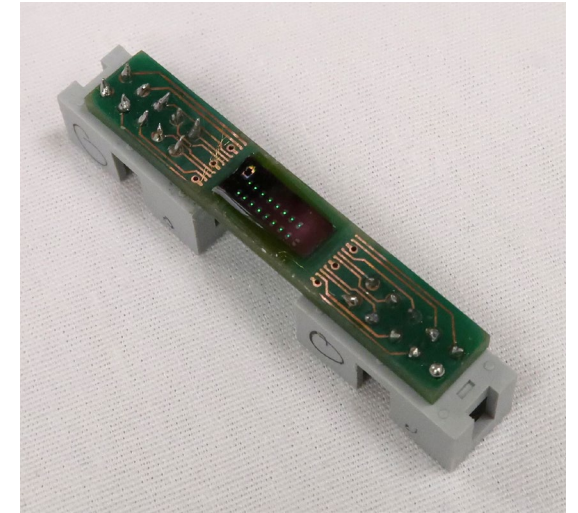
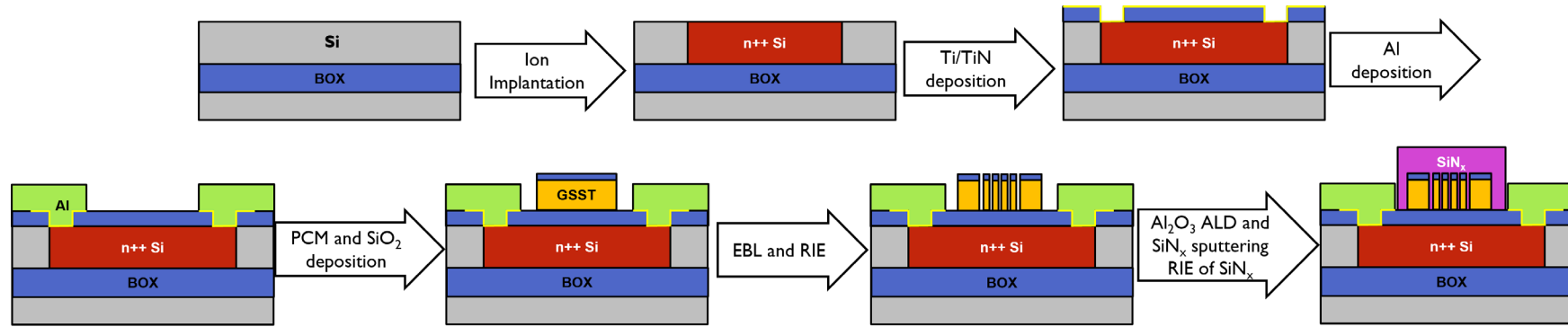
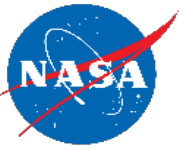
Exploiting the extraordinary refractive index contrast in PCMs to unprecedented functionalities in photonic components



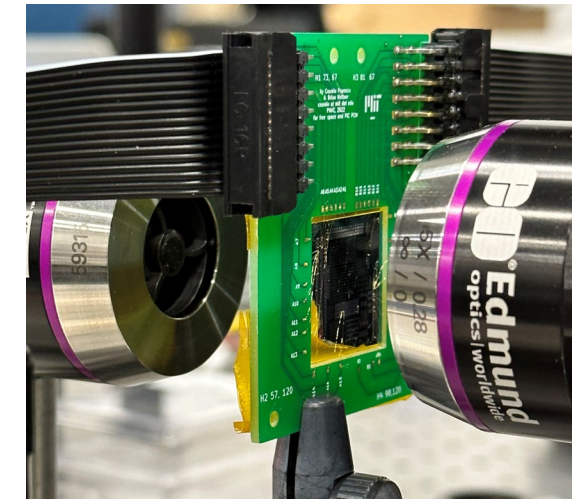
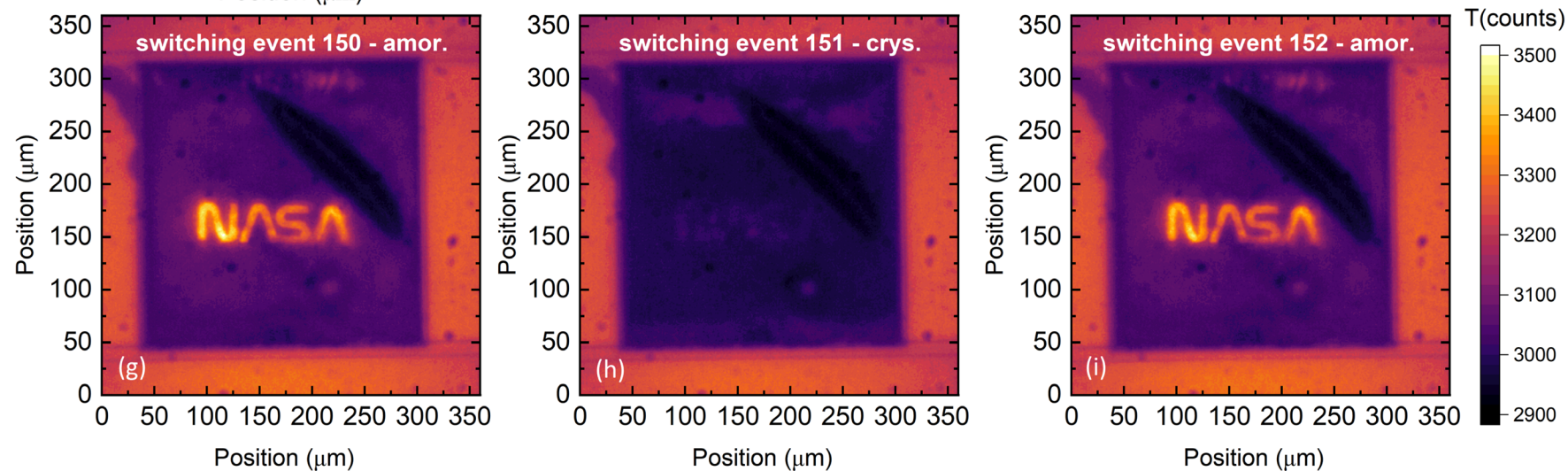
An example: PCM-based Actively Tunable Filter

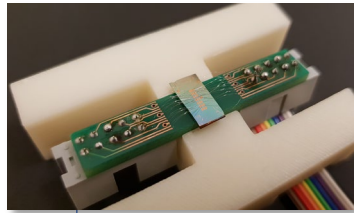


Reshaping light using PCM-based tunable filters

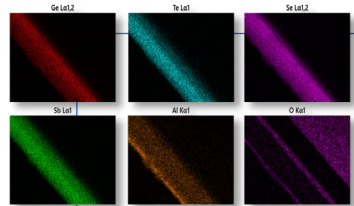


Packaged PROWESS filter

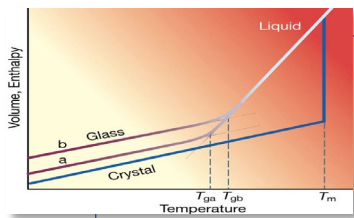




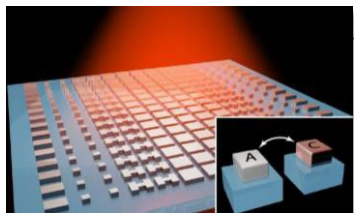
Electrical switching of PCM metasurfaces



Long live PCMs: mitigating failure mechanisms

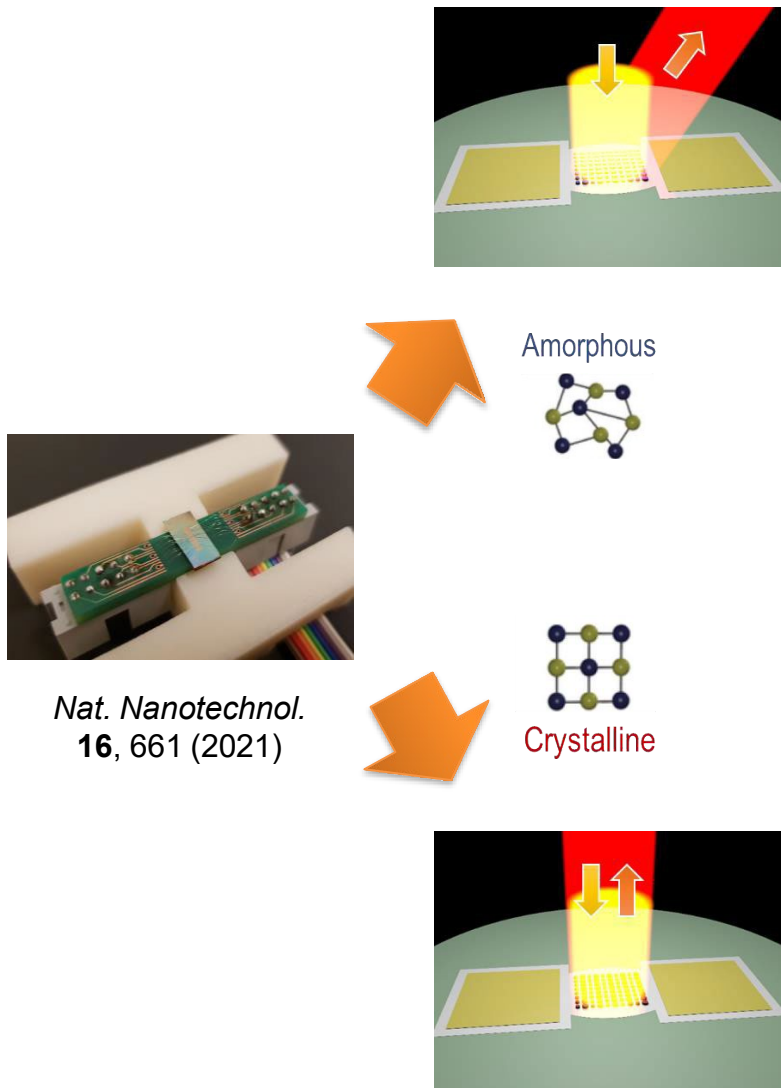


Beware the pitfalls: thermal modeling of PCMs [EL12.08 / 10:15am talk]



Reshaping light using PCM metasurfaces

Electrical switching of PCM metasurfaces



Optics in
2021

Metasurfaces Embracing a Phase Change

RESEARCHERS

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Clayton M. Fowler and Hualiang Zhang, University of Massachusetts, Lowell, MA, USA

REFERENCES

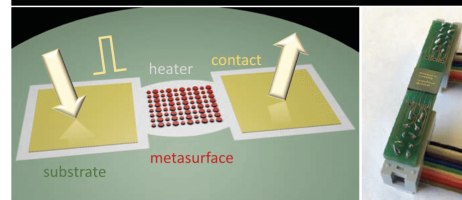
1. Y. Zhang et al. *Nat. Commun.* **10**, 4279 (2019).
2. M.Y. Shalaginov et al. *Nat. Commun.* **12**, 1225 (2021).
3. Y. Zhang et al. *Nat. Nanotechnol.* **16**, 461 (2021).
4. Y. Wang et al. *Nat. Nanotechnol.* **16**, 657 (2021).

Recent progress in nanophotonics has enabled planar optical systems, termed metasurfaces, that hold potential to enable agile light manipulation and provide size, weight, power and cost (SWaP-C) benefits compared with traditional optics. Active metasurfaces, the optical properties of which can be modulated post-fabrication, have attracted a surge of interest in recent years, given their broad potential applications in imaging, sensing, display and optical ranging. A cohort of non-mechanically switchable meta-devices has been already demonstrated; however, most of them either operate within a limited tun-

ing range or are made of optical phase-change materials. More specifically, we have synthesized a new class of nonvolatile chalcogenide alloys, Ge₂Sb₂Se₂Te₂, exhibiting giant index contrast as well as broadband transparency in both amorphous and crystalline states.¹

Capitalizing on this material platform and metasurface design innovation, we demonstrated an all-dielectric varifocal metalens in mid-infrared.² By annealing the entire metasurface, we showed that the lens shifted its focal plane between the distances of 1.5 mm and 2 mm and produced multi-depth imaging with diffraction-limited resolution and a

? Lifetime: 50 cycles



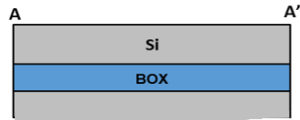
Top: Rendering of a Ge₂Sb₂Se₂Te₂ varifocal metalens. The focal-spot position is shifted by changing the crystallinity of the phase-change-material meta-atoms collectively. Bottom: Illustration of an on-chip, electrically switchable metasurface with beam-steering functionality, and photograph of a metasurface chip wire-bonded onto a custom-made printed circuit board.

of a tunable metasurface and produced a record half-octave spectral shift with a large relative optical contrast exceeding 400%. By exploiting the same device architecture, we also prototyped a polarization-insensitive deflector for beam steering.

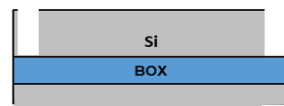
Our advances in phase-change-material meta-optics demonstrate that active metasurfaces can achieve optical quality on par with conventional precision bulk optics involving mechanical moving parts. The work points to exciting applications fully unleashing the SWaP-C benefits of active-metasurface optics. [DOI](#)

Electrical switching of PCM metasurfaces

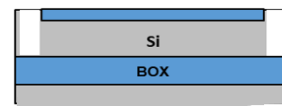
(1) SOI wafer



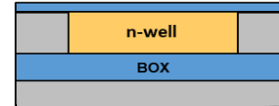
2) Etch (220nm) isolation rings



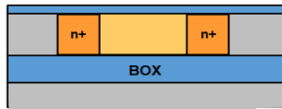
3) Grow screening SiO₂ (14nm)



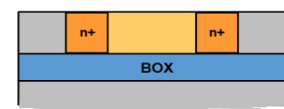
4) Implant n wells



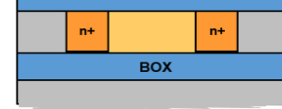
(5) Implant n+



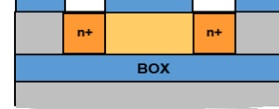
6) RTA 7s/1000C, strip screening oxide



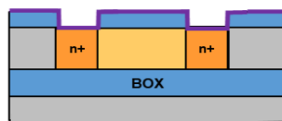
7) Grow SiO₂ (10nm)



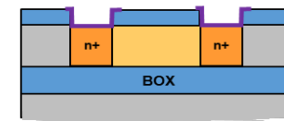
8) Open contact holes



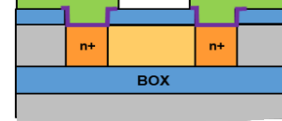
9) Deposit 10nmTi / 20nmTiN contact liner, 700C RTA



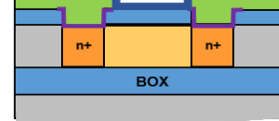
10) Pattern and etch Ti/TiN Contact Liner



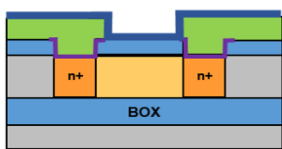
11) Pattern, deposit 200nm Al, liftoff for contacts



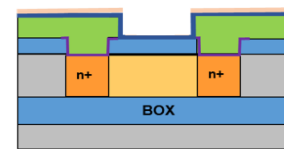
12) Deposit 10nm SiO₂ passivation



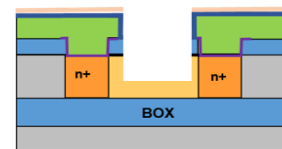
13) Backside polishing



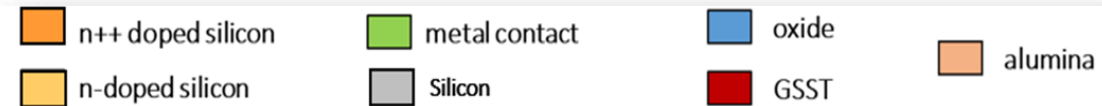
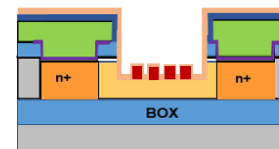
14) Deposit ZEP + Ebeam Patterning



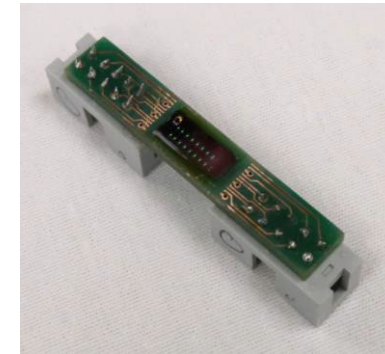
15) RIE – etch SiO2 then Si



(16) Metasurface patterning



(17) SiN capping layer

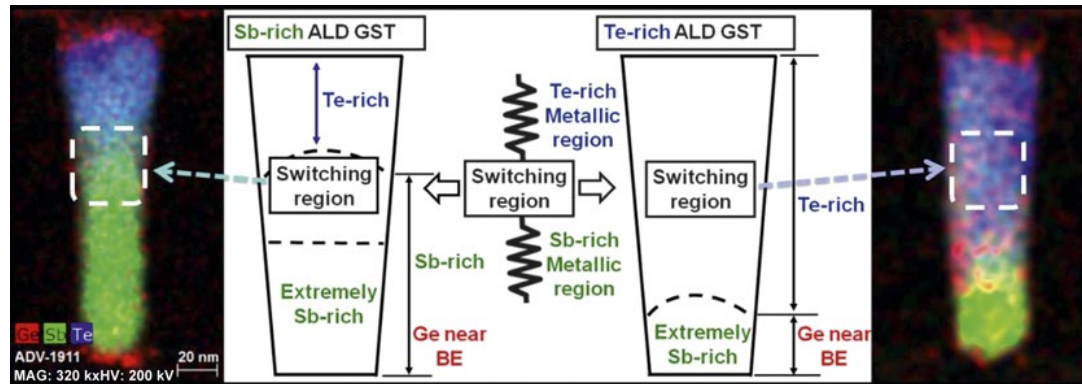


Packaged PCM metasurface devices

Failure mechanism of electronic PCMemories

Driving Force	Voltage-Bias Polarity Dependence	Atomic Motion			Working Phase	Force Intensity
		Ge	Sb	Te		
Incongruent melting	No	Ge-rich "solid" phase	Sb,Te-rich "liquid" phase		Solid, liquid	-
Wind force (by hole carrier)	Yes	Toward (-) electrode	Toward (-) electrode	Toward (-) electrode	Dominant in solid	Gentle
Electrostatic force	Yes	Toward (-) electrode	Toward (-) electrode	Toward (+) electrode	Dominant in liquid	Strong

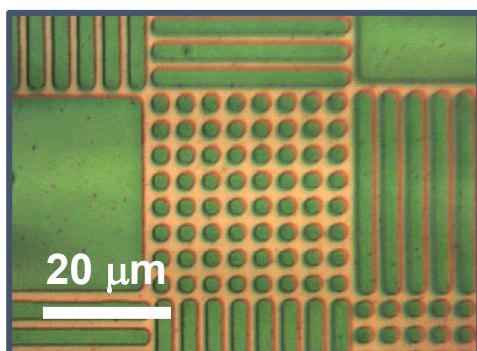
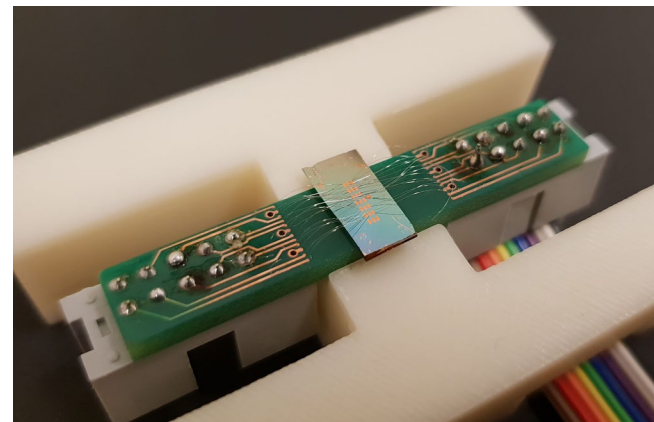
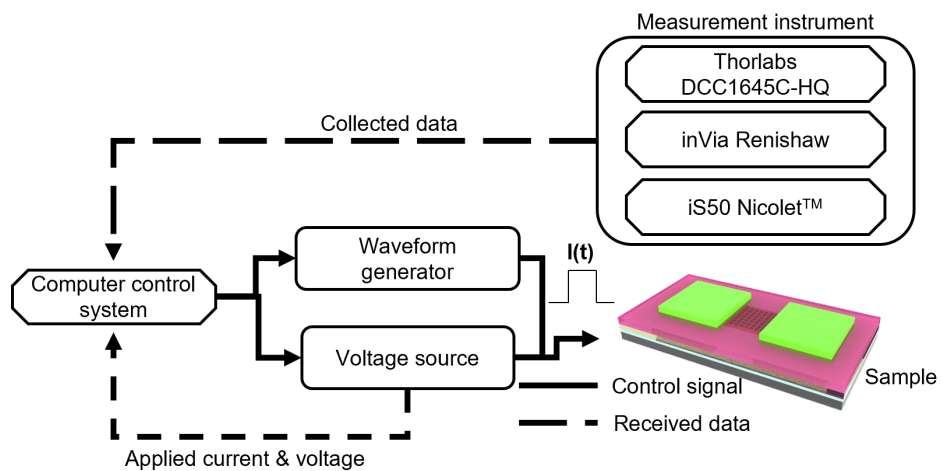
Not relevant to optical PCMs!



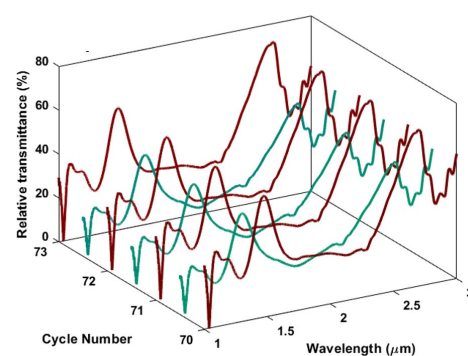
Electromigration induced void formation and elemental segregation

MRS Bull. 44, 710-714 (2019)

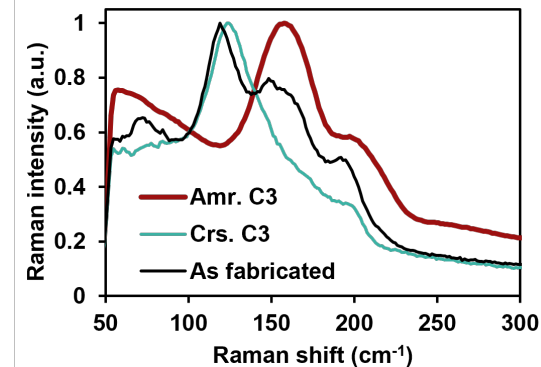
Multimode in-situ characterization platform



Imaging

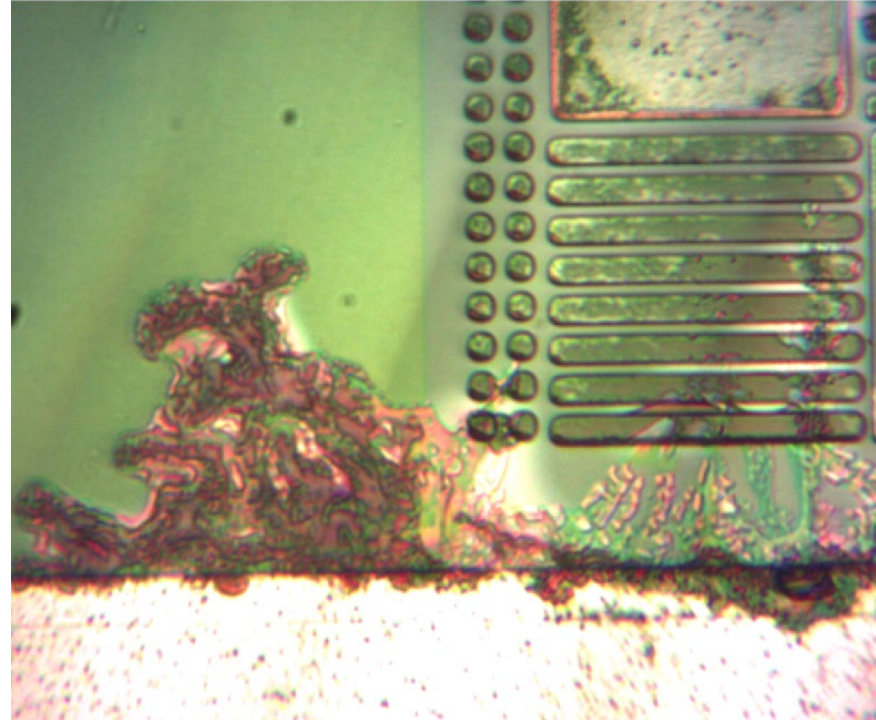
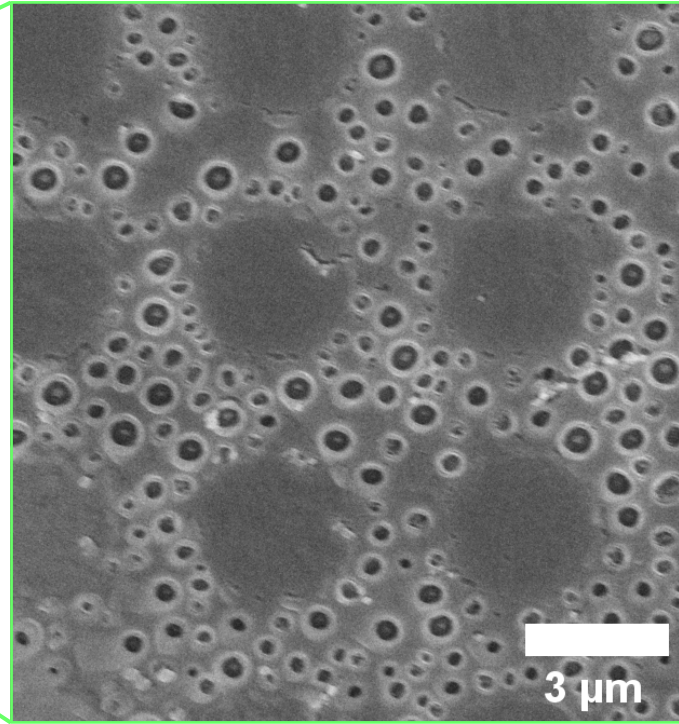
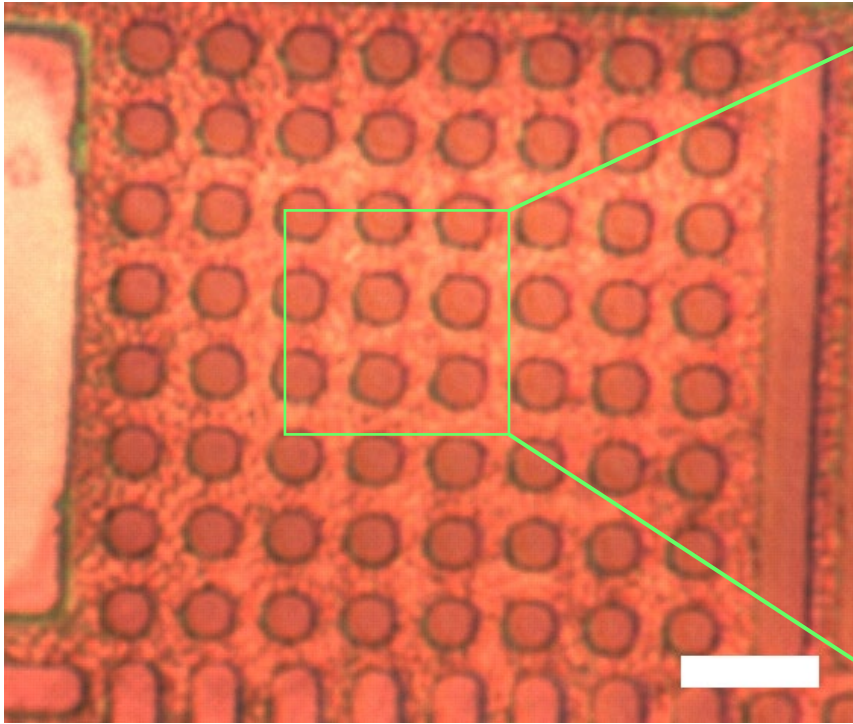


Micro-FTIR



Raman spectroscopy

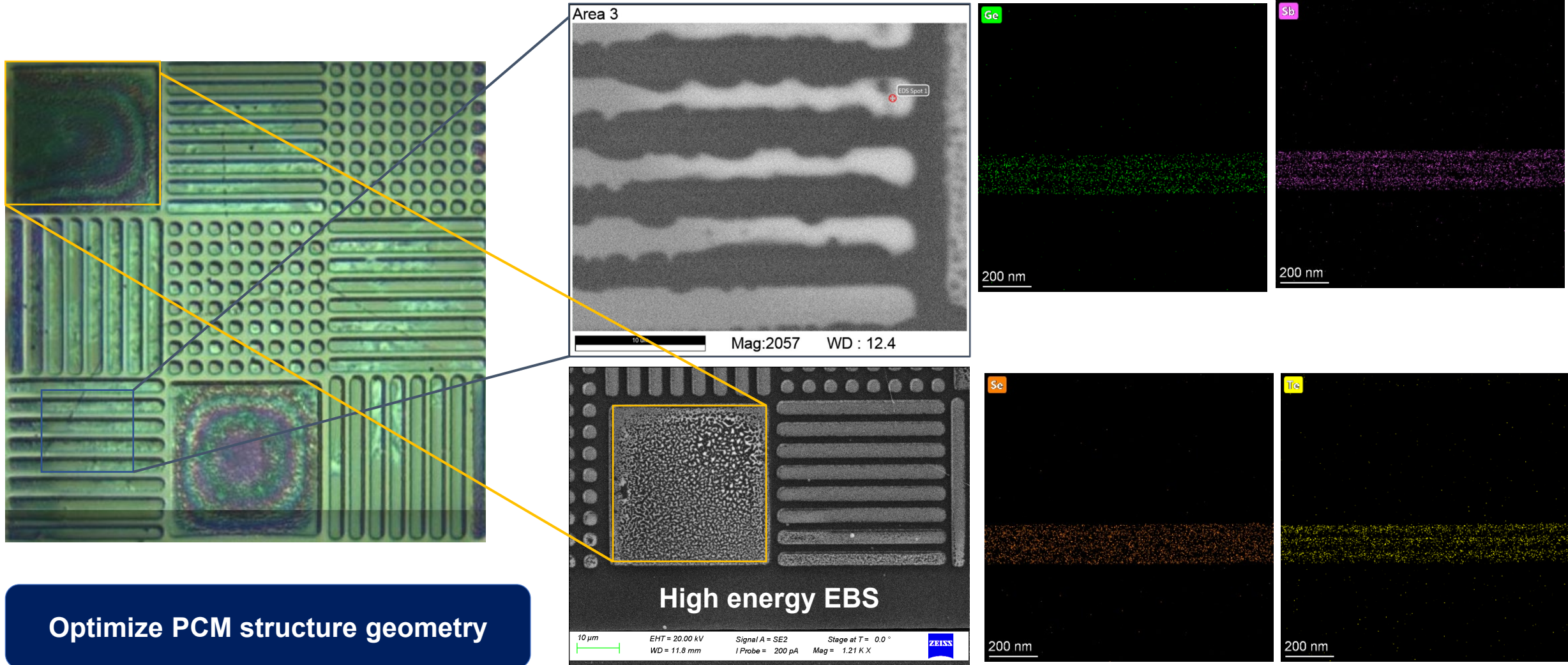
H-release from SiN capping layer & Electromigration of metal contacts



Switching from PECVD SiN to H-free sputtered SiN

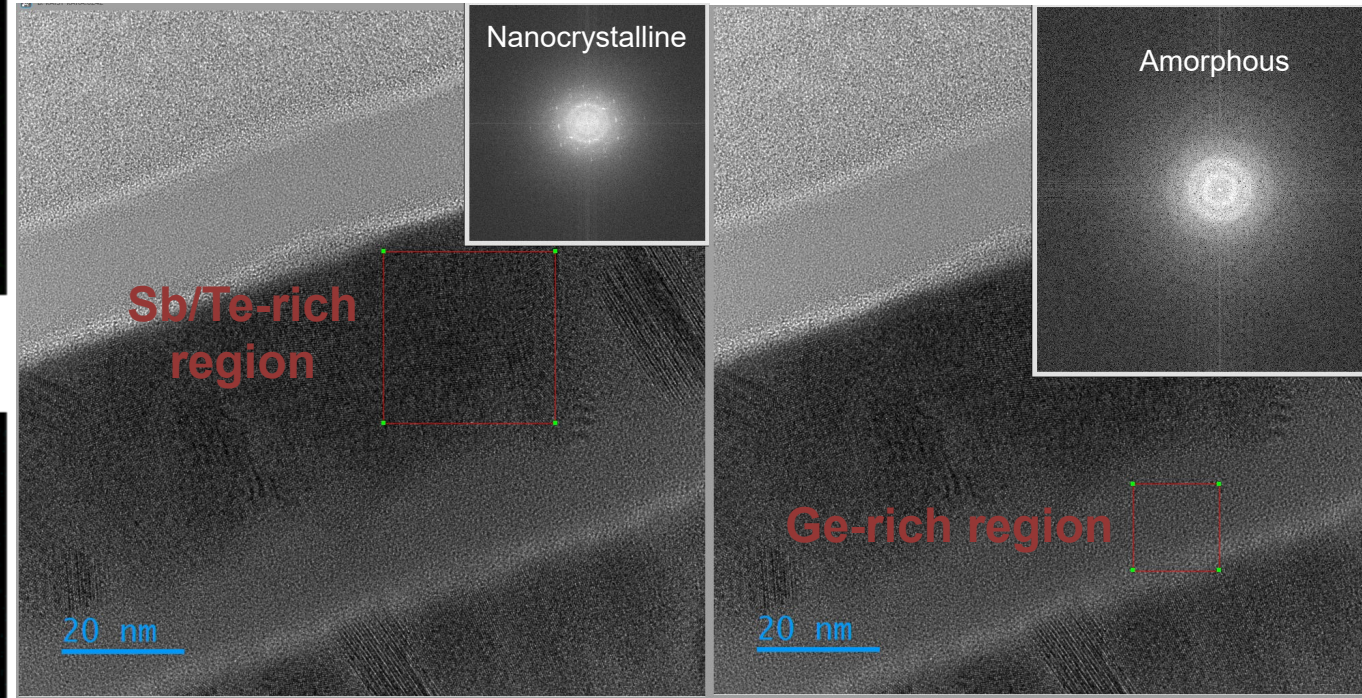
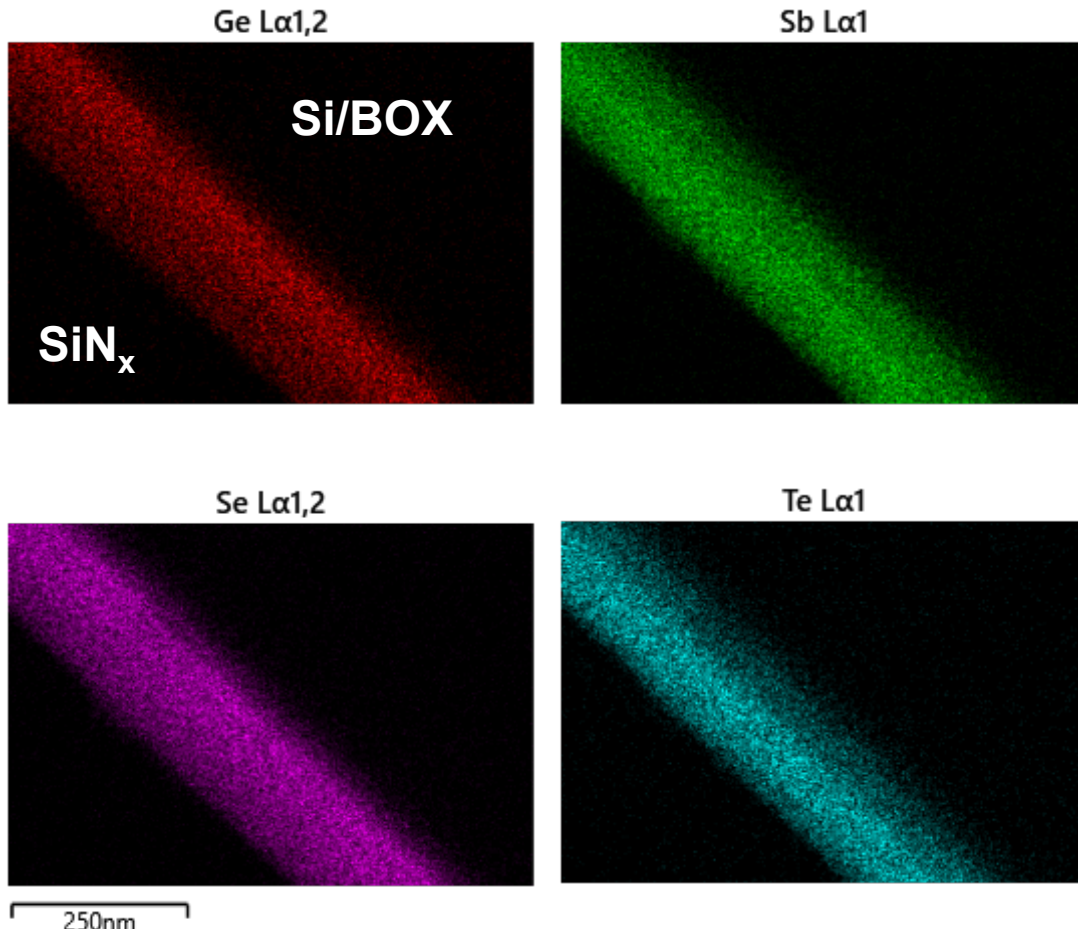
Using AC bias voltage

Morphological instability & Compositional non-uniformity



Optimize PCM structure geometry

Elemental segregation during cycling



Ge segregation prevents crystallization

Ge migrates to high-T region whereas Sb and Te moves to low-T region

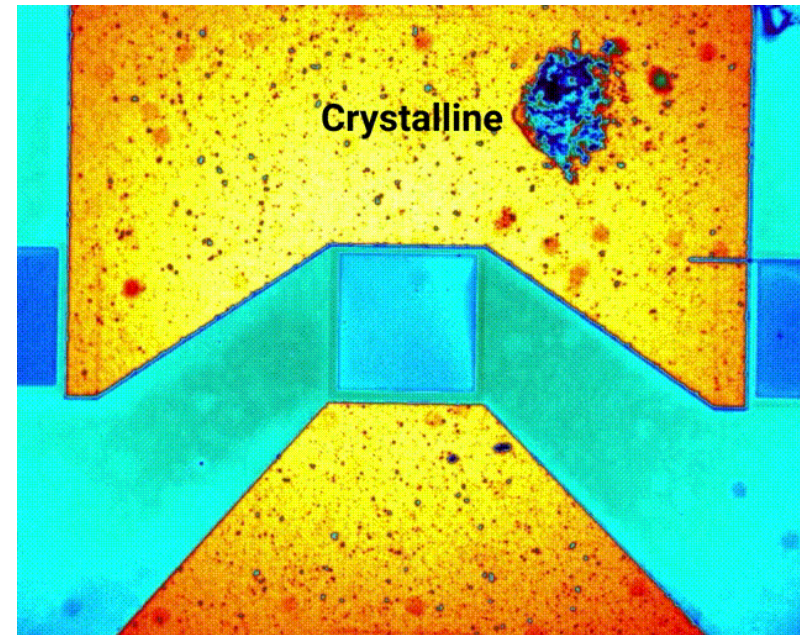
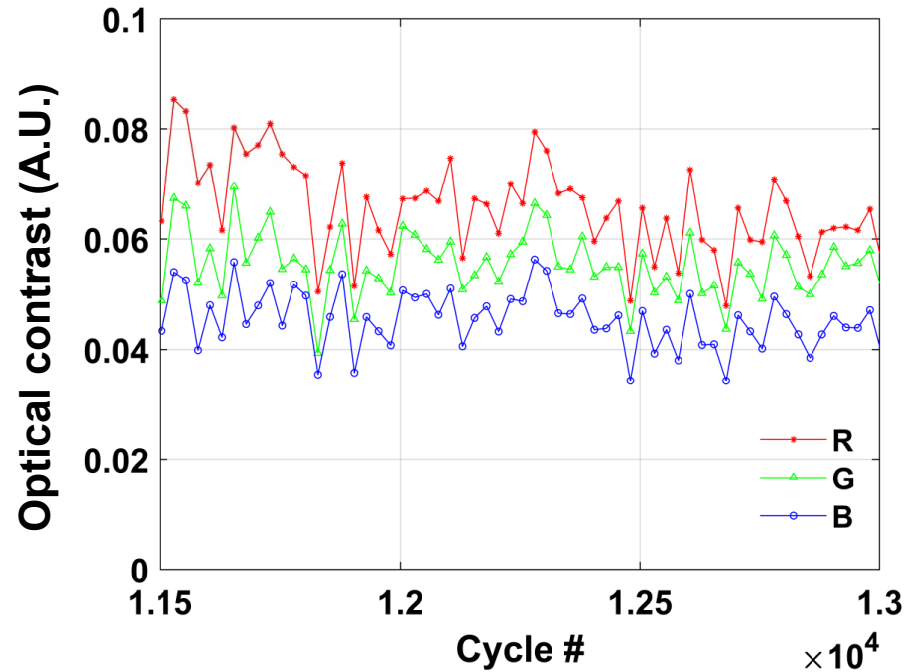
Increasing liquid phase dwell time

Endurance improvement in large-volume optical PCM switching



PCM switching volume: $\sim 4,000 \mu\text{m}^3$

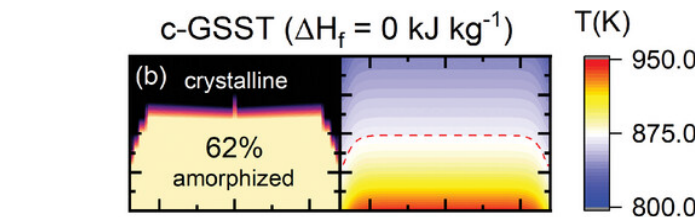
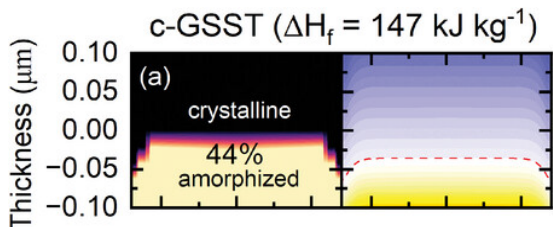
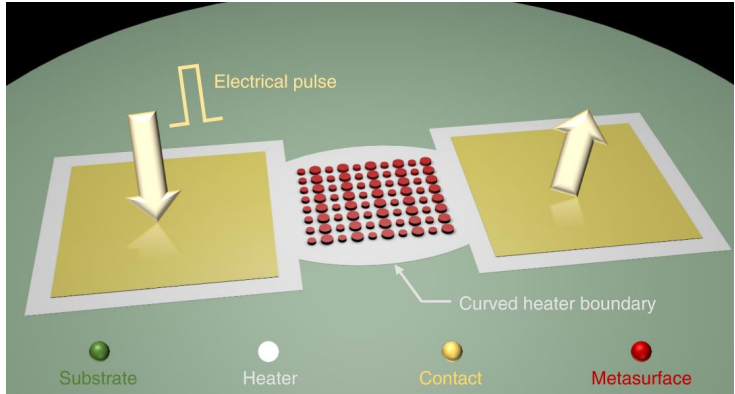
100 million times larger than that in PCMemories!



Large-area PCM switching with endurance of over 60,000 cycles

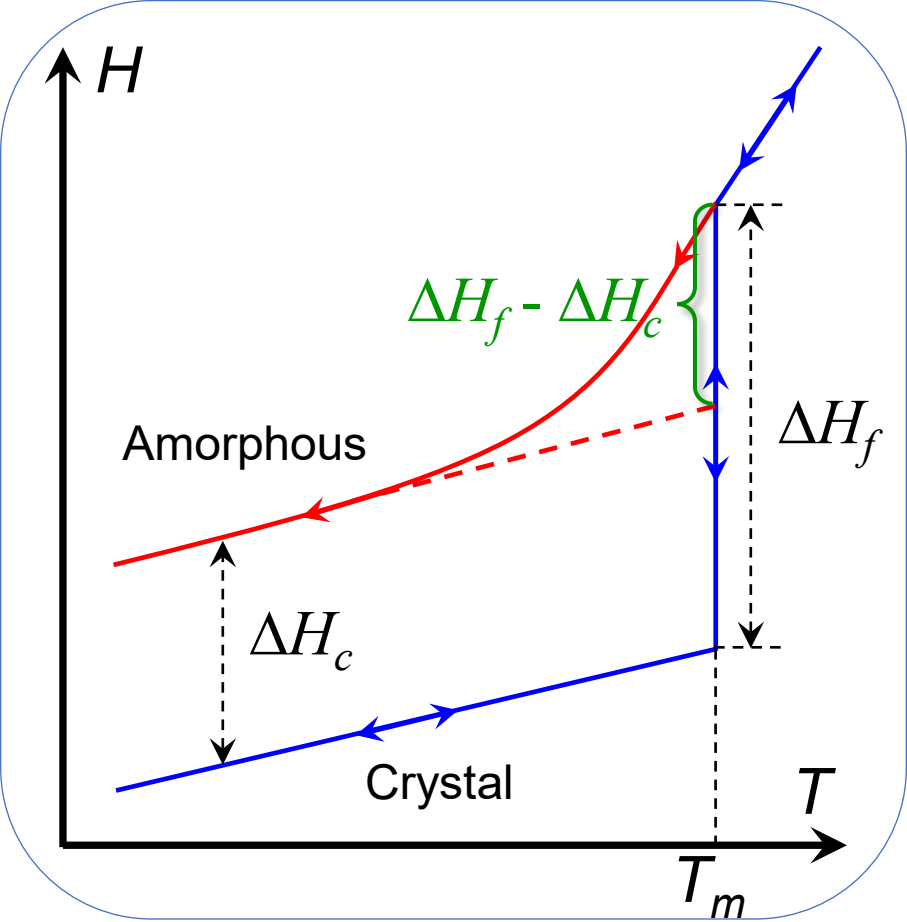
Thermal modeling of PCM devices

Thermal modeling is critical to device optimization and improving endurance

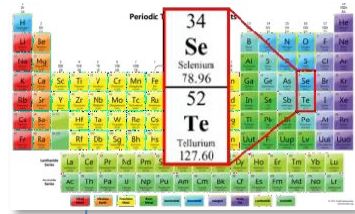


	Si	SiO ₂	Si ₃ N ₄	am-GSST	cry-GSST	Graphene	Al ₂ O ₃	Au
Density [kg m ⁻³]	2329	2203	3100	5267	5267	2250	3900	19 300
Specific heat [J kg ⁻¹ K ⁻¹]	700	740	700	275	351	420	900	129
Thermal conductivity [Wm ⁻¹ K ⁻¹]	150	1.38	20	0.2	0.4	160 ^[90]	30	317
Relative permittivity	-	-	-	-	-	4.708	-	6.9
Electrical conductivity [S m ⁻¹]	-	-	-	-	-	1/(d·R _{sh})	-	45.6 × 10 ⁶

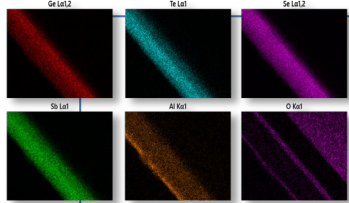
Constants?



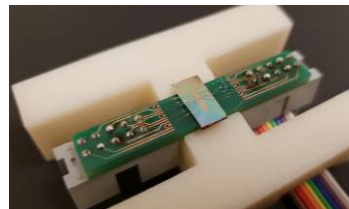
- ❑ Fundamental behavior studying on the effect of enthalpy of melting on solidification of PCMs as part of controlling phase change kinetics (Small, <https://doi.org/10.1002/sml.202304145>, 2023)
- ❑ Scaling up phase change material-based devices



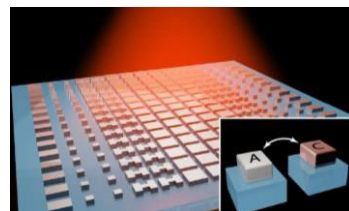
With their low optical loss, large index change and switching volume, **PCMs are an ideal materials for active / reconfigurable metasurface optics**



Electrically reconfigurable PCM photonic circuits and metasurfaces have been demonstrated leveraging Si foundry processing

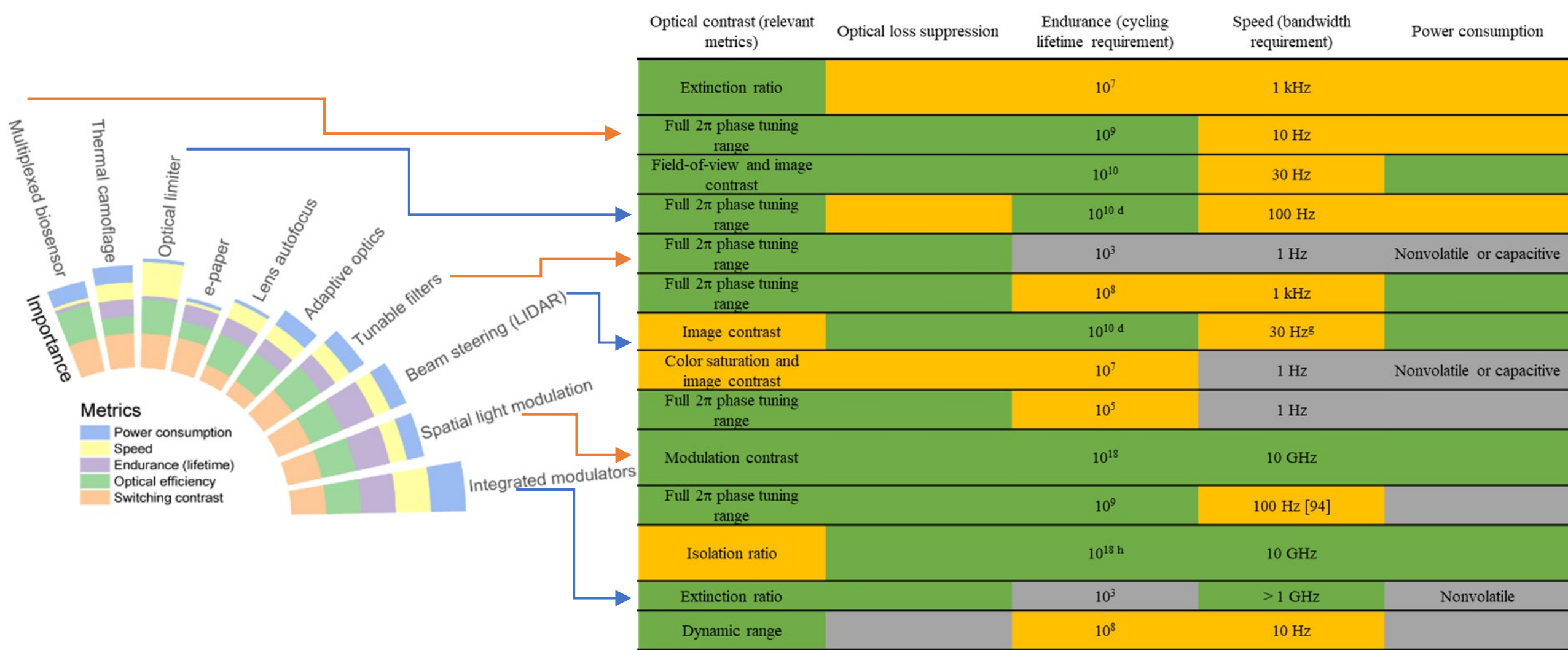


Understanding and **mitigating failure mechanisms** enable electrical switching of PCM metasurfaces over tens of thousands of cycles (and likely more)



Temperature dependence of heat capacity and thermal conductivity of PCMs must be accounted for to enable **accurate thermal modeling**

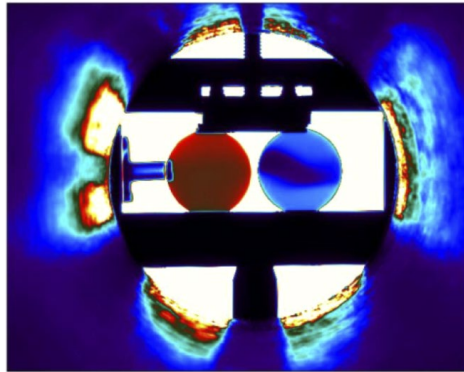
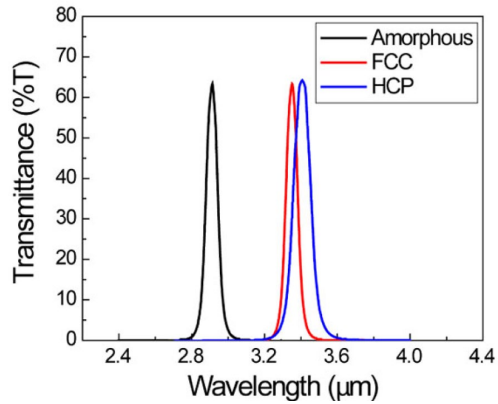
Application-driven trade study



References (H. J. Kim *et al.*)



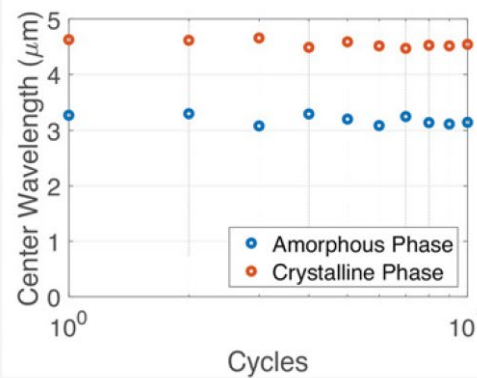
P-ACTIVE tunability & gas sensing



Optica **7(7)** 746 (2020)

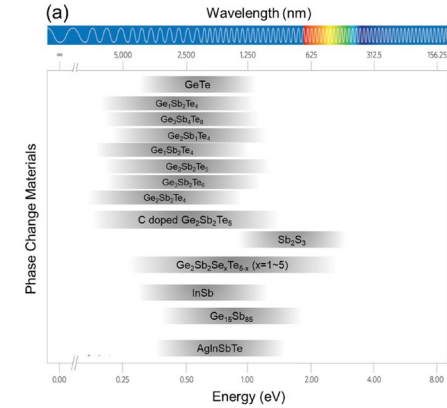
Optics Express **28(7)**, 10583 (2020)

Reliability test



Optical Eng. **60(8)** (2020)

PCM-net database

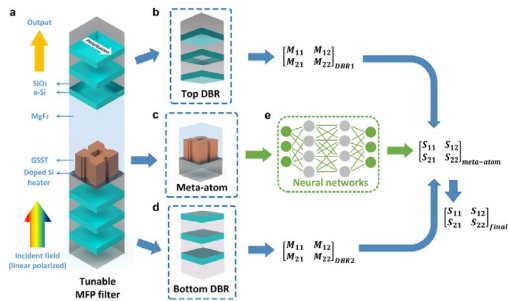


J. Phys. Photo. **3**, 024008 (2021)



A Multi-Spectral Imaging Pyrometer Patent *Applica.*(2022)

DNN design



NASA/TP-20220019141



P-ACTIVE Project Report

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